Vishay Semiconductors





Cathode

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LINKS TO ADDITIONAL RESOURCES

Anode 2 C



PRIMARY CHARACTERISTICS				
I _{F(AV)}	16 A			
V _R	600 V			
V _F at I _F	0.91 V			
t _{rr}	55 ns			
T _J max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Single			

FEATURES

- Ultrafast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _{solder pad} = 141 °C	16	٨		
Non-repetitive peak surge current	I _{FSM}	T_J = 25 °C, 6 ms square pulse	160	A		

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-		
Forward voltage	¥-	I _F = 16 A	-	1.04	1.25	V	
Forward voltage V _F	٧F	I _F = 16 A, T _J = 150 °C	-	0.91	1.1		
Reverse leakage current	1	$V_{R} = V_{R}$ rated	-	-	15		
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	70	300	μA	
Junction capacitance	CT	V _R = 600 V	-	16	-	pF	

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RoHS COMPLIANT HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I _F = 1 A, dI _F /dt = 50 A	õs, V _R = 30 V	-	55	-	
Poverse recevery time	+	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr}$	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	55	
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 16 A, dI _F /dt = 500 A/μs, V _B = 400 V	-	100	-	ns
		T _J = 125 °C		-	150	-	
Poole recovery ourrent		T _J = 25 °C		-	20	-	•
Peak recovery current	I _{RRM}	T _J = 125 °C		-	27	-	A
	0	T _J = 25 °C		-	1	-	μC
Reverse recovery charge Q _{rr}	Q _{rr}	T _J = 125 °C		-	2	-	μΟ

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C		
Thermal resistance, junction to mount	R _{thJM}		-	1.2	1.7	°C/W		
Approximate weight				0.55		g		
Marking device		Case style SMPD (TO-263AC)		16EI	DU06			

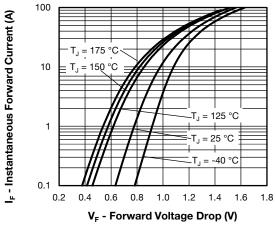


Fig. 1 - Typical Forward Voltage Drop Characteristics

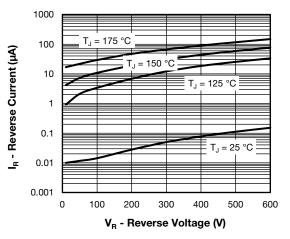


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-16EDU06HM3

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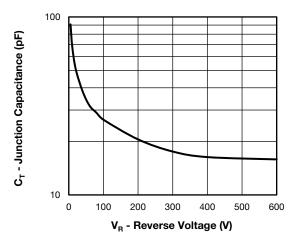


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

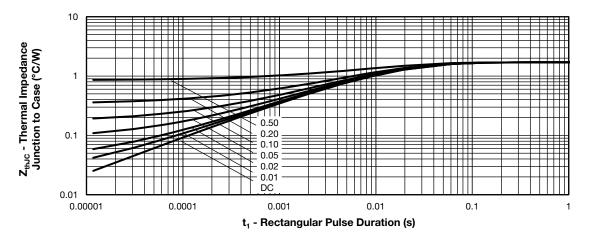
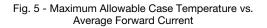


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

180 Allowable Case Temperature (°C) 175 170 165 160 DC 155 150 Square wave (D = 0.50) 145 80 % rated $V_{\rm R}$ applied 140 135 See note (1) 130 6 16 18 0 2 4 8 10 12 14 I_{F(AV)} - Average Forward Current (A)



Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 5);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_{R} (1 - D); I_{R} \text{ at } V_{R1} = \text{rated } V_{R} \end{array}$

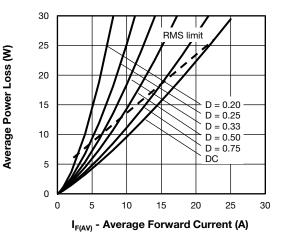


Fig. 6 - Forward Power Loss Characteristics

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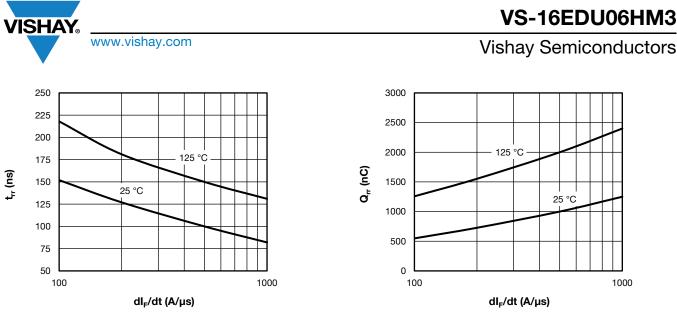


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt

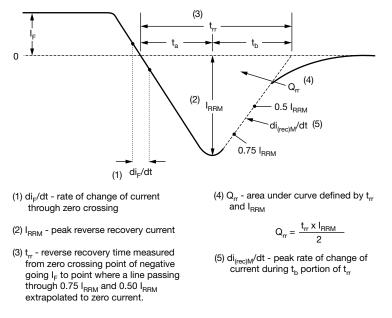


Fig. 9 - Reverse Recovery Waveform and Definitions

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Device code	VS-	16	E	D	U	06	н	M3
	1	2	3	4	5	6	7	8
	1	- Visl	nay Sen	nicondu	ctors pr	oduct		
	2	- Cur	rent rati	ing (16 A	4)			
	3	- Circ	cuit cont	figuratio	n:			
		E =	single c	lie				
	4	- D =	SMPD	packag	е			
	5	- Pro	cess typ	be,				
		U =	ultrafas	st recove	ery			
	6	- Vol	tage coo	de (06 =	600 V)			
	7	- H=	AEC-Q	101 qua	alified			
	8	- M3	= halog	en-free,	RoHS-	complia	ant, and	termina

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-16EDU06HM3/I	2000	2000	13" diameter plastic tape and reel					

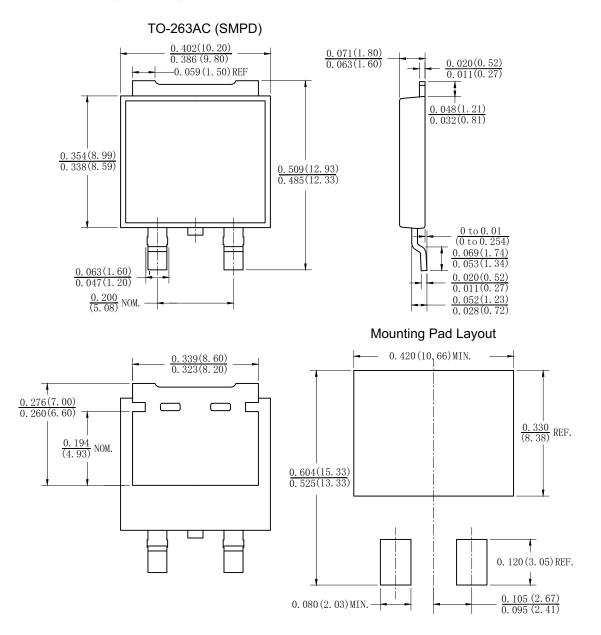
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96771				





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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